

## In situ cooling and heating study of VO<sub>2</sub> phase transition

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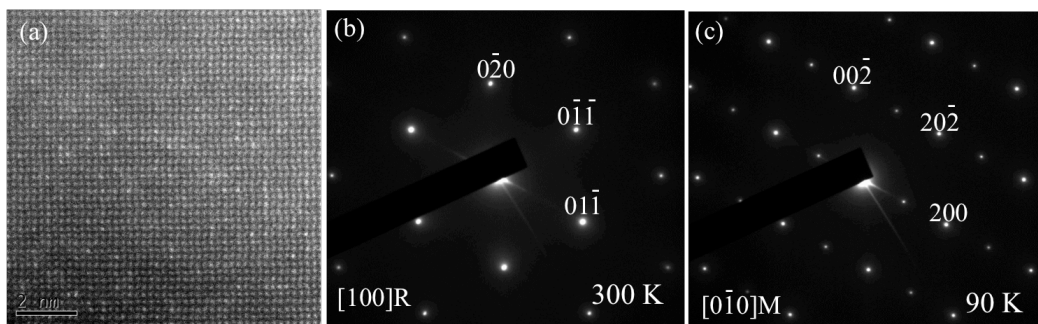
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Vanadium dioxide (VO<sub>2</sub>), one the correlated electron material has received many attentions through a metal-insulator transition (MIT) at ~ 340°K, close to room temperature. The transition in VO<sub>2</sub> associated by structural phase transition from the monoclinic (M<sub>1</sub>), insulating phase, to rutile(R), metallic phase. This metal-insulator transition is accompanied by a noticeable resistivity, optical transparency and magnetic changes. In addition, large hysteresis effects are reported at nanoscale size VO<sub>2</sub>, which opens much more application possibility such as gas sensors and optical data storage. However, there is still no clear explanation on hysteresis effect variations of different VO<sub>2</sub> morphologies.

In this work, we used aberration corrected scanning transition electron microscopy and in situ transition electron microscopy (TEM) cooling and heating techniques to study the different VO<sub>2</sub> samples. The atomic resolution image of W-doped sample (x=0.8 atom %) Figure 1a. and corresponding diffraction patterns at 300 and 90 K are respectively shown in Figure 1b-c. This investigation correlates the atomic structural aspect of each sample to variations in hysteresis gap, which help controlling of the hysteresis properties for different needs.



**Figure 1.** (a) Atomic resolution HAADF image of  $W_xV_{1-x}O_2$  nanowires ( $x=0.8$  atom%). (a-b) are SAED patterns of an individual single-crystalline nanowire at the 300 °K and 90 °K respectively.